

• Power switching circuits



ULTRA FAST RECOVERY POWER RECTIFIER

Absolute Maximum Ratings (per diode) T_C=25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{RRM}	Peak Repetitive Reverse Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current @ T _C = 100°C	30	A	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	180	A	
T _{J,} T _{STG}	Operating Junction and Storage Temperature	- 65 to +150	°C	

Thermal Characteristics

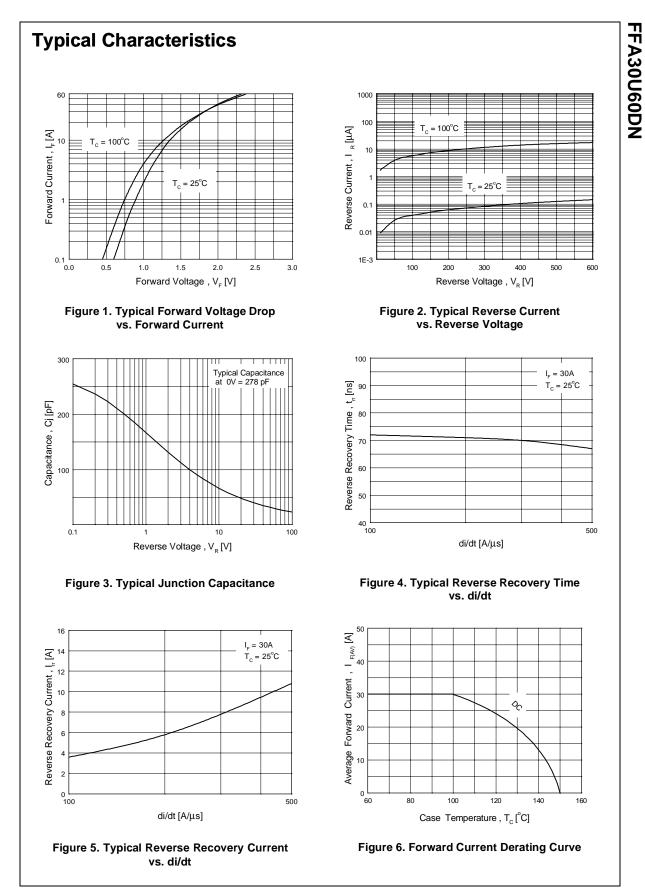
Symbol	Parameter	Value	Units
$R_{ extsf{ heta}JC}$	Maximum Thermal Resistance, Junction to Case	0.8	°C/W

Electrical Characteristics (per diode) T_C=25 °C unless otherwise noted

Symbol	Parameter		Min.	Тур.	Max.	Units
V _{FM} *	Maximum Instantaneous Forward Voltage					V
	I _F = 30A	T _C = 25 °C	-	-	2.3	
	I _F = 30A	T _C = 25 °C T _C = 100 °C	-	-	2.1	
RM *	Maximum Instantaneous Reverse Current					μΑ
	@ rated V _R	T _C = 25 °C	-	-	15	
		T _C = 25 °C T _C = 100 °C	-	-	150	
rr	Maximum Reverse Recovery Time		-	-	90	ns
rr	Maximum Reverse Recovery Current		-	-	8	А
2 _{rr}	Maximum Reverse Recovery Charge		-	-	360	nC
	(I _F =30A, di/dt = 200A/µs)					
W _{AVL}	Avalanche Energy		1.0	-	-	mJ

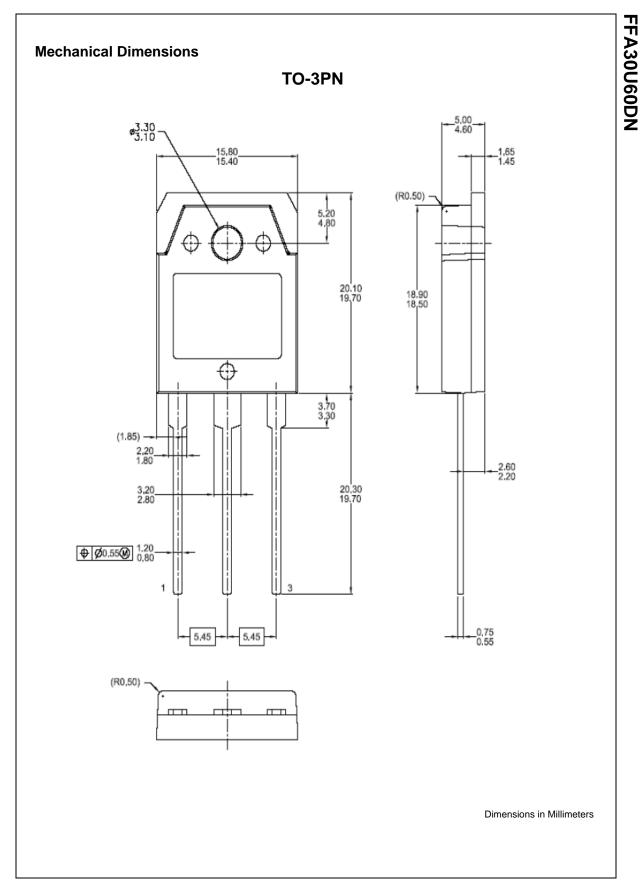
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